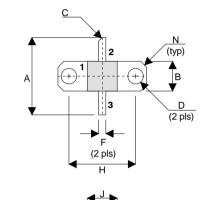
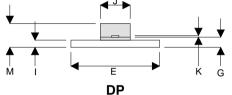


METAL GATE RF SILICON FET

MECHANICAL DATA





PIN₂

DRAIN

PIN 1 SOURCE

PIN₃ **GATE**

DIM	mm	l ol.	Inches	l ol.
Α	16.51	0.25	0.650	0.010
В	6.35	0.13	0.250	0.005
С	45°	5°	45°	5°
D	3.30	0.13	0.130	0.005
Е	18.92	0.08	0.745	0.003
F	1.52	0.13	0.060	0.005
G	2.16	0.13	0.085	0.005
Н	14.22	0.08	0.560	0.003
	1.52	0.13	0.060	0.005
J	6.35	0.13	0.250	0.005
K	0.13	0.03	0.005	0.001
М	5.08	0.51	0.200	0.020
N	1.27 x 45°	0.13	0.050 x 45°	0.005

GOLD METALLISED MULTI-PURPOSE SILICON DMOS RF FET 20W - 28V - 500MHzSINGLE ENDED

FEATURES

- SIMPLIFIED AMPLIFIER DESIGN
- SUITABLE FOR BROAD BAND APPLICATIONS
- · LOW Cree
- USEFUL P_O AT 1GHz
- LOW NOISE
- HIGH GAIN 13 dB MINIMUM

APPLICATIONS

 HE/VHF/UHF COMMUNICATIONS from 1 MHz to 1 GHz

ABSOLUTE MAXIMUM RATINGS (T_{case} = 25°C unless otherwise stated)

$\overline{P_D}$	Power Dissipation	50W
BV_DSS	Drain – Source Breakdown Voltage	70V
BV_GSS	Gate – Source Breakdown Voltage	±20V
I _{D(sat)}	Drain Current	5A
T _{stg}	Storage Temperature	−65 to 150°C
T _i	Maximum Operating Junction Temperature	200°C

Semelab Ltd reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

Website: http://www.semelab.co.uk



ELECTRICAL CHARACTERISTICS (T_{case} = 25°C unless otherwise stated)

Parameter		Test Conditions		Min.	Тур.	Max.	Unit
RV	Drain-Source	V _{GS} = 0	I _D = 100mA	70			V
BV _{DSS}	Breakdown Voltage	v _{GS} = 0	ID = 100IIIA	70			V
I _{DSS}	Zero Gate Voltage	\/ 29\/	V _{GS} = 0			1	mA
	Drain Current	$V_{DS} = 28V$				ı	IIIA
I _{GSS}	Gate Leakage Current	V _{GS} = 20V	V _{DS} = 0			1	μА
V _{GS(th)}	Gate Threshold Voltage*	I _D = 10mA	$V_{DS} = V_{GS}$	1		7	V
9 _{fs}	Forward Transconductance*	V _{DS} = 10V	I _D = 1A	0.8			S
G _{PS}	Common Source Power Gain	P _O = 20W		13			dB
η	Drain Efficiency	V _{DS} = 28V	$I_{DQ} = 0.2A$	50			%
VSWR	Load Mismatch Tolerance	f = 500MHz		20:1			_
C _{iss}	Input Capacitance	V _{DS} = 28V	$V_{GS} = -5V$ $f = 1MHz$			60	pF
C _{oss}	Output Capacitance	V _{DS} = 28V	$V_{GS} = 0$ $f = 1MHz$			30	pF
C _{rss}	Reverse Transfer Capacitance	V _{DS} = 28V	$V_{GS} = 0$ $f = 1MHz$			2.5	pF

^{*} Pulse Test: Pulse Duration = 300 μs , Duty Cycle $\leq 2\%$

HAZARDOUS MATERIAL WARNING

The ceramic portion of the device between leads and metal flange is beryllium oxide. Beryllium oxide dust is highly toxic and care must be taken during handling and mounting to avoid damage to this area.

THESE DEVICES MUST NEVER BE THROWN AWAY WITH GENERAL INDUSTRIAL OR DOMESTIC WASTE.

THERMAL DATA

R _{THj-case}	Thermal Resistance Junction – Case	Max. 3.5°C / W
-----------------------	------------------------------------	----------------

Semelab Ltd reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

Semelab plc. Telephone +44(0)1455 556565. Fax +44(0)1455 552612.

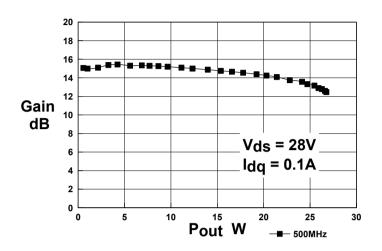
Document Number 6217

Issue 2

E-mail: sales@semelab.co.uk

Website: http://www.semelab.co.uk





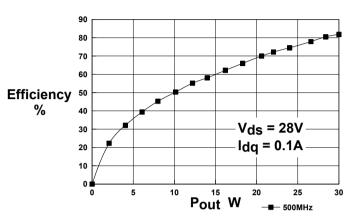


Figure 1 Gain vs. Output Power

Figure 2 Efficiency vs. Output Power

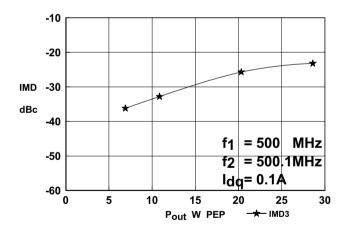


Figure 3 IMD vs. Output Power

Semelab Ltd reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

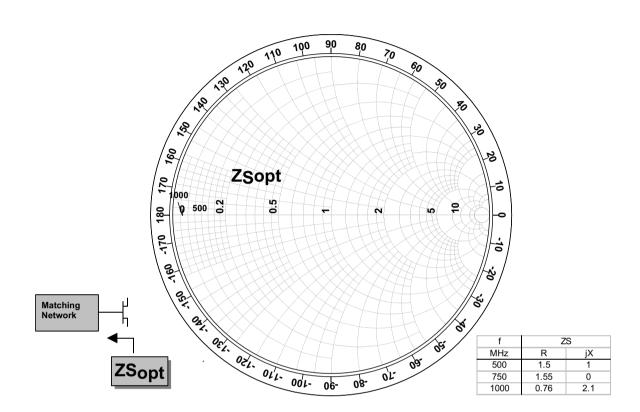
Website: http://www.semelab.co.uk

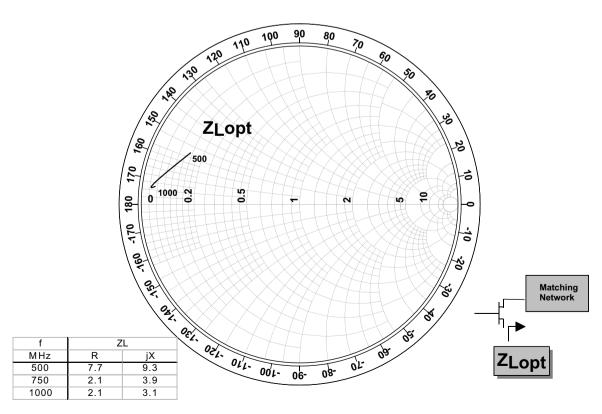
Semelab plc. Telephone +44(0)1455 556565. Fax +44(0)1455 552612. E-mail: sales@semelab.co.uk

Document Number 6217

Issue 2







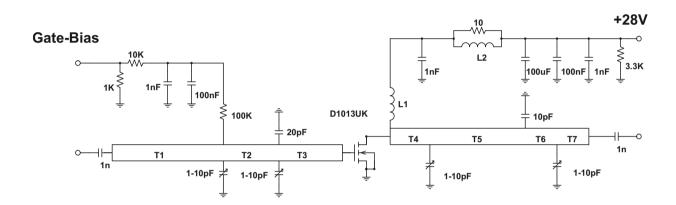
Semelab Ltd reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

Semelab plc. Telephone +44(0)1455 556565. Fax +44(0)1455 552612.

Document Number 6217 Issue 2

E-mail: sales@semelab.co.uk Website: http://www.semelab.co.uk





500MHz Test Fixture

Substrate 0.8 mm FR4, Er = 2.2All microstrip lines W = 2.2mm

T1 35mm

T2 15mm

T3 10mm

T4 14mm

T5 30mm

T6 6mm

T7 12.5mm

5.5 turns 20swg enamelled copper wire 7mm i.d. L1

1.5 turns 24swg enamelled copper wire on Siemens B62152A7X 2 hole L2

Semelab Ltd reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

Semelab plc. Telephone +44(0)1455 556565. Fax +44(0)1455 552612.

E-mail: sales@semelab.co.uk

Website: http://www.semelab.co.uk

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

TT Electronics: